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NTE1398 Integrated Circuit Dual Audio Power Amplifier, 5.8W/Ch

Absolute Maximum Ratings: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Operating Supply Voltage	18V
DC Supply Voltage	26V
Peak Supply Voltage (Note 1)	50V
Output Current (Per Channel)	4A
Power Dissipation (Per Package)	15W
Operating Temperature Range, T_{opr}	-20° to $+70^\circ\text{C}$
Storage Temperature Range, T_{stg}	-55° to $+125^\circ\text{C}$
Junction Temperature, T_J	$+150^\circ\text{C}$

Note 1. Pulse width = 200ms, $T_{rise} \geq 1\text{ms}$

Electrical Characteristics: ($T_A = +25^\circ\text{C}$, $V_{CC} = 13.2\text{V}$, $f = 1\text{kHz}$, $R_L = 4\Omega$, One-Half Operation unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
Quiescent Current	I_Q	$V_{in} = 0$		40	80	160	mA
Input Bias Voltage	V_B	$V_{in} = 0$		—	—	40	mV
Voltage Gain	G_V	$V_{in} = 2.45\text{mV}$		53	55	57	dB
Difference of Voltage Gain	ΔG_V	$V_{in} = 2.45\text{mV}$		—	—	± 1.5	dB
Output Power Per Channel	P_{out}	$R_L = 4\Omega$, $THD = 10\%$	$V_{CC} = 13.2\text{V}$	5.0	5.8	—	W
			$V_{CC} = 14.4\text{V}$	—	7.0	—	W
Total Harmonic Distortion	THD	$P_{out} = 0.5\text{W}$		—	0.15	1.0	%
Noise Output	WBN	$R_g = 10\text{k}\Omega$, $BW = 20\text{Hz}$ to 20kHz		—	1.0	2.0	mV
Supply Voltage Rejection Ratio	SVR	$R_g = 600\Omega$, $f = 500\text{Hz}$		30	40	—	dB
Input Resistance	R_{in}	$f = 1\text{kHz}$		—	30	—	k Ω
Rolloff Frequency	f_l	$G_V = 3\text{dB}$ from $f = 1\text{kHz}$ Ref	Low	—	40	—	Hz
	f_h		High	—	25	—	kHz
Crosstalk	CT	$f = 500\text{Hz}$, $R_g = 600\Omega$		40	58	—	dB

Pin Connection Diagram
(Front View)

